

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Tc = +25°С
40V	6.5mΩ @ V _{GS} = 10V	85A
	9.8mΩ @ V _{GS} = 4.5V	70A

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP, and is ideal for use in:

PowerDI5060-8

- Motor controls
- **DC-DC** converters
- Load switches

Features

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching Ensures More Reliable and Robust End Application
- Thermally Efficient Package Cooler Running Applications
- High Conversion Efficiency
- Low RDS(ON) Minimizes On-State Losses
- Low Input Capacitance
- Fast Switching Speed
- <1.1mm Package Profile Ideal for Thin Applications
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3) The DMTH4007LPSQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/guality/product-definitions/

Mechanical Data

- Package: PowerDI[®]5060-8 •
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.097 grams (Approximate)

Bottom View Top View



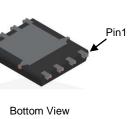
Notes:

Site 1:

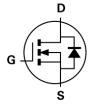
PowerDI5060-8/SWP (Type UX)

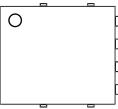


Top View



Pin1





Internal Schematic

Internal Schematic

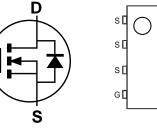


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ΠD

ΠD



Top View Pin Configuration

Ordering Information (Note 4)

Part Number	Package	Packing		
Fait Nulliber	Fackage	Qty.	Carrier	
DMTH4007LPSQ-13	PowerDI5060-8	2500	Tape & Reel	
DMTH4007LPSQ-13	PowerDI5060-8/SWP (Type UX)	2500	Tape & Reel	

1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free

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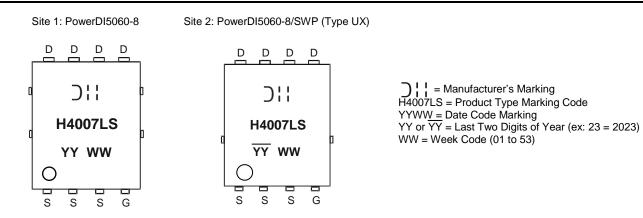
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

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Marking Information



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Units
Drain-Source Voltage			VDSS	40	V
Gate-Source Voltage			Vgss	±20	V
Continuous Drain Current, V _{GS} = 10V (Note 5)		T _A = +25°C T _A = +100°C	ID	15 11	А
Continuous Drain Current, V _{GS} = 10V (Note 6)	Steady State	Tc = +25°C Tc = +100°C	ID	85 60	А
Maximum Continuous Body Diode Forward Current (Note 6)			ls	85	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			ldм	340	A
Avalanche Current, L = 0.1mH			I _{AS}	20	A
Avalanche Energy, L = 0.1mH			Eas	20	mJ

Thermal Characteristics

Characteristic		Symbol	Value	Units
Total Power Dissipation (Note 5)	T _A = +25°C	PD	2.7	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R _{0JA}	55	°C/W
Total Power Dissipation (Note 6)	Tc = +25°C	PD	83.3	W
Thermal Resistance, Junction to Case (Note 6)		Rejc	1.8	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate. 6. Thermal resistance from junction to soldering point (on the exposed drain pad).



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

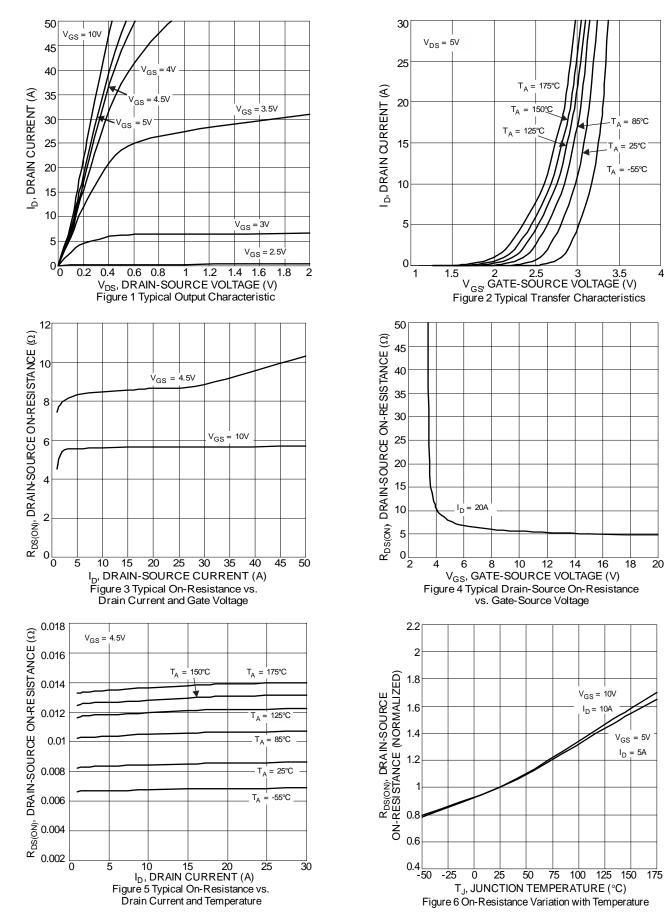
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)	Oymbol		176	max	Unit	
Drain-Source Breakdown Voltage	BVpss	40	_		V	$V_{GS} = 0V, I_D = 1mA$
Zero Gate Voltage Drain Current	IDSS	_	_	1	μA	$V_{DS} = 32V, V_{GS} = 0V$
Gate-Source Leakage	IGSS	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)				1		
Gate Threshold Voltage	VGS(th)	1	—	3	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$
Static Drain-Source On-Resistance		_	5.4	6.5		V _{GS} = 10V, I _D = 20A
Static Drain-Source On-Resistance	R _{DS(ON)}	_	8.4	9.8	mΩ	$V_{GS} = 4.5V, I_D = 20A$
Diode Forward Voltage	Vsd	_	—	1.2	V	V _{GS} = 0V, I _S = 20A
DYNAMIC CHARACTERISTICS (Note 8)			•	•		÷
Input Capacitance	Ciss	_	1895		pF	V _{DS} = 30V, V _{GS} = 0V, f = 1MHz
Output Capacitance	Coss		485			
Reverse Transfer Capacitance	Crss	_	20.9			
Gate Resistance	Rg	0.1	0.62	1.8	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	12.4	_		
Total Gate Charge (V _{GS} = 10V)	Qg	_	29.1		nC	V _{DS} = 30V, I _D = 20A
Gate-Source Charge	Qgs	_	5.9		ne	
Gate-Drain Charge	Q _{gd}	_	3.5	_		
Turn-On Delay Time	t _{D(on)}		5.4	_		
Turn-On Rise Time	tR		4.5	_		$V_{DD} = 30V, V_{GS} = 10V,$ $I_D = 20A, R_G = 3\Omega$
Turn-Off Delay Time	tD(off)	_	16.2	—	ns	
Turn-Off Fall Time	tF	_	3.5			
Body Diode Reverse-Recovery Time	t _{RR}		30.6	_	ns	
Body Diode Reverse-Recovery Charge	Qrr		28.1	—	nC	IF = 20A, di/dt = 100A/µs

 7. Short duration pulse test used to minimize self-heating effect.
8. Guaranteed by design. Not subject to product testing. Notes:



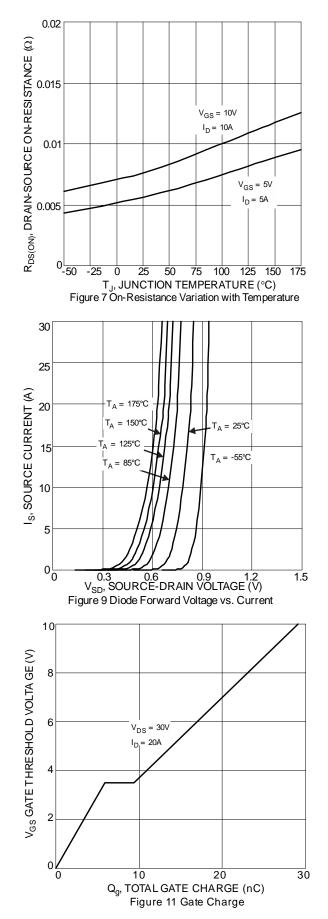
DMTH4007LPSQ

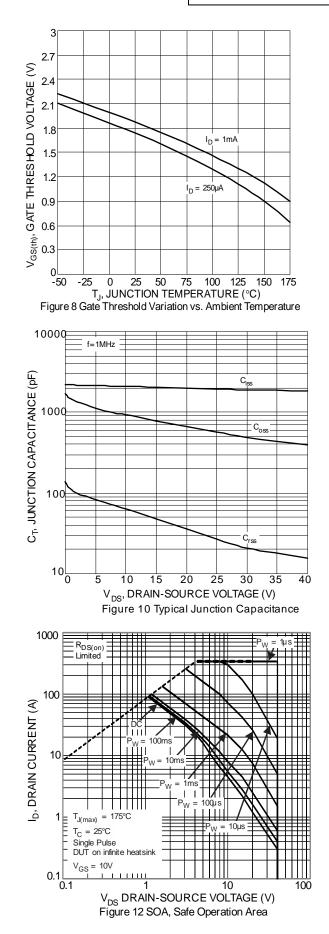
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DMTH4007LPSQ Document number: DS37797 Rev. 3 - 2

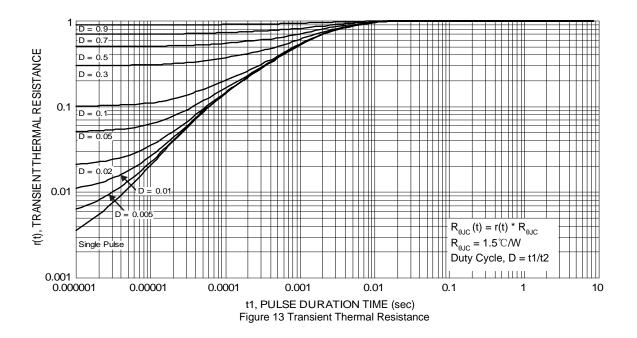






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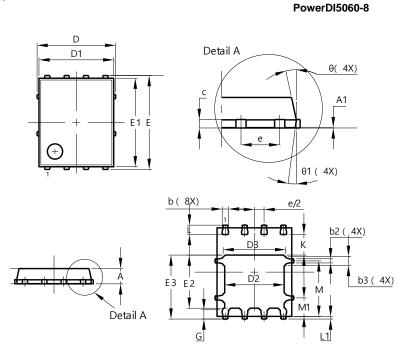




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

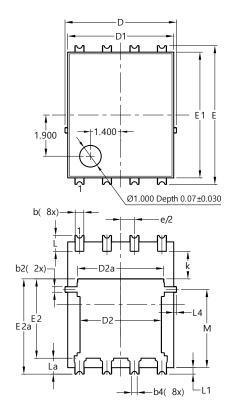
Site 1:

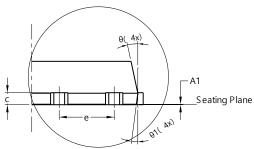


	PowerDI5060-8				
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0.00	0.05	-		
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
С	0.230	0.330	0.277		
D		5.15 BSC	;		
D1	4.70	5.10	4.90		
D2	3.70	4.10	3.90		
D3	3.90	4.30	4.10		
E	(6.15 BSC	;		
E1	5.60	6.00	5.80		
E2	3.28	3.68	3.48		
E3	3.99	4.39	4.19		
е	1.27 BSC				
G	0.51	0.71	0.61		
К	0.51	-	-		
L	0.51	0.71	0.61		
L1	0.100	0.200	0.175		
М	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
Θ	10°	12°	11°		
Θ1	6°	8°	7°		
Al	All Dimensions in mm				

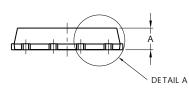
Site 2:

PowerDI5060-8/SWP (Type UX)





DETAIL A



PowerDI5060-8/SWP (Type UX)				
Dim	Min	Max	Тур	
Α	0.90	1.10	1.00	
A1	0	0.05		
b	0.30	0.50	0.41	
b2	0.20	0.35	0.25	
b4).25REF	-	
С	0.230	0.330	0.277	
D	-	.15 BS(C	
D1	4.70	5.10	4.90	
D2	3.56	3.96	3.76	
D2a	3.78	4.18	3.98	
ш	6.40 BSC			
E1	5.60	6.00	5.80	
E2	3.46	3.86	3.66	
E2a	4.195	4.595	4.395	
е	1	.27BSC)	
k	1.05			
L	0.635	0.835	0.735	
La	0.635	0.835	0.735	
L1	0.200	0.400	0.300	
L1a	0	.050RE		
L4	0.025	0.225	0.125	
Μ	3.205	4.005	3.605	
θ	10°	12°	11°	
θ1	6°	8°	7°	
All	Dimensi	ions in	mm	

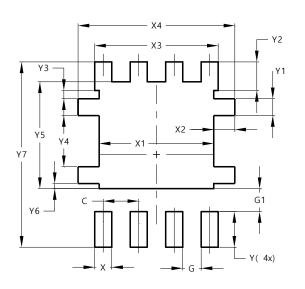
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Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

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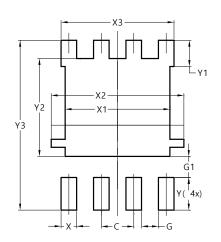


Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	0.755
X3	4.420
X4	5.610
Y	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610

Site 2:

PowerDI5060-8/SWP (Type UX)

PowerDI5060-8



Dimensions	Value (in mm)	
С	1.270	
G	0.660	
G1	0.820	
Х	0.610	
X1	4.100	
X2	5.190	
X3	4.420	
Y	1.270	
Y1	1.020	
Y2	3.810	
Y3	6.610	



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